

SKiiP® 3

2-pack-integrated intelligent Power System

SKiiP 2413 GB123-4DFL V3

Features

- SKiiP technology inside
- Trench IGBTs
- CAL HD diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- Fiber optic interface
- UL recognized File no. E63532

Typical Applications*

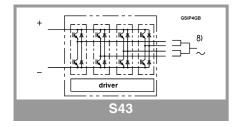
- Renewable energies
- Traction
- Elevators
- · Industrial drives

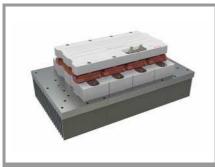
Footnotes

1) With assembly of suitable MKP capacitor per terminal

Absolute	Maximum Ratings		T _s = 25°C unless otherwise	specified		
Symbol	Conditions		Values	Unit		
System	•					
V _{CC} 1)	Operating DC link	oltage	900	V		
V _{isol}	DC, t = 1 s, main te	rminals to heat sink	4300	V		
I _{t(RMS)}	per AC terminal, T _{te}	rminal <115°C	400	Α		
I _{FSM}	$T_j = 150 {}^{\circ}\text{C}, t_p = 10$	ms, sin 180°	13500	Α		
l ² t	$T_j = 150 {}^{\circ}\text{C}, t_p = 10$	ms, diode	911	kA ² s		
f _{out}	fundamental output	t frequency	1	kHz		
T _{stg}	storage temperatur	е	-40 85	°C		
IGBT						
V _{CES}	T _j = 25 °C		1200			
I _C	T _i = 150 °C	T _s = 25 °C	2280	Α		
	1 _j = 150 C	T _s = 70 °C	1756	Α		
I _{Cnom}			2400	Α		
T _j	junction temperature		-40 150	°C		
Diode						
V_{RRM}	T _j = 25 °C		1200	V		
I _F	T _i = 150 °C	T _s = 25 °C	1807	Α		
1j = 150 C	T _s = 70 °C	1370	Α			
I _{Fnom}	_		1860	Α		
T _j	junction temperature		-40 150 °			
Driver						
Vs	power supply		13 30	V		
V_{iH}	input signal voltage (high)		15 + 0.3	V		
V _{isoIPD}	QPD <= 10pC, PRI	M to POWER	1170	V		
dv/dt	secondary to prima	ry side	75	kV/μs		
f _{sw}	switching frequency	у	8	kHz		

Characteristics		$T_s = 25^{\circ}C$ unless otherwise specified				
Symbol	Conditions		min.	typ.	max.	Unit
IGBT						
V _{CE(sat)}	I _C = 1200 A	T _j = 25 °C		1.7	2.1	V
	at terminal	T _j = 125 °C		1.9		V
V _{CE0}		T _j = 25 °C		0.90	1.10	V
		T _j = 125 °C		0.80	1.00	V
r _{CE}	at terminal	T _j = 25 °C		0.7	0.8	mΩ
at terrima	T _j = 125 °C		0.9	1.1	mΩ	
E _{on} + E _{off}	$E_{on} + E_{off}$ $I_C = 1200 A$	$V_{CC} = 600 \text{ V}$		442		mJ
	T _j = 125 °C	V _{CC} = 900 V		780		mJ
R _{th(j-s)}	per IGBT switch				0.015	K/W
$R_{th(j-r)}$	per IGBT switch				0.015	K/W





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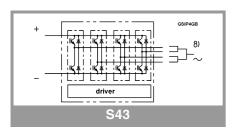
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1) With assembly of suitable MKP capacitor per terminal

Characte	ristics		Γ _s = 25°C ι	ınless oth	erwise sp	ecified
Symbol	Conditions		min.	typ.	max.	Unit
Diode			•			
$V_F = V_{EC}$	I _F = 1200 A	T _j = 25 °C		1.50	1.80	V
	at terminal	T _j = 125 °C		1.50		V
V _{F0}		T _j = 25 °C		0.9	1.10	٧
		T _j = 125 °C		0.7	0.90	٧
r _F	at terminal	T _j = 25 °C		0.5	0.6	mΩ
	at terminal	T _j = 125 °C		0.7	8.0	mΩ
E _{rr}	I _F = 1200 A	V _R = 600 V		84		mJ
	T _j = 125 °C	V _R = 900 V		112		mJ
R _{th(j-s)}	per diode switch			0.029	K/W	
R _{th(j-r)}	per diode switch			0.048	K/W	
Driver						
Vs	supply voltage non	stabilized	13	24	30	V
I _{S0}	bias current @V _s =2	$4V, f_{sw} = 0, I_{AC} = 0$		330		mA
Is	$k_1 = 55 \text{ mA/kHz}, k_2$	$= 0.00035 \text{ mA/A}^2$	= 330	+ k ₁ * f _{sw}	$+ k_2 * I_{AC}^2$	mA
V_{IT+}	input threshold volt	12.3			V	
V _{IT-}	Input threshold volt			4.6	V	
R _{IN}	input resistance		10		kΩ	
C _{IN}	input capacitance			1		nF
t _{pRESET}	error memory reset		0.0122		ms	
t _{TD}	top / bottom switch interlock time			3		μs
t _{jitter}	jitter clock time			125		ns
t _{SIS}	short pulse suppression time			0.625	0.7	μs
I _{TRIPSC}	over current trip level		2940	3000	3060	A _{PEAK}
T_{trip}	over temperature trip level		110	115	120	°C
V_{DCtrip}	over voltage trip lev			not impl.		V
t _{d(on)IO}	V _{CC} = 900 V I _C = 1200 A	input-output turn-on propagation time		1.4		μs
t _{d(off)IO}	$T_{j} = 1200 \text{ A}$ $T_{j} = 25 \text{ °C}$	input-output turn-off propagation time	1.4			μs
System						
R _{th(r-a)}	flow rate=390m ³ /h, above sea level	flow rate=390m³/h, T _a =25°C, 500m above sea level			0.0255	K/W
R _{CC'+EE'}		measured per switch, T _s = 25 °C		0.13		mΩ
L _{CE}	commutation inductance		3			nΗ
C _{CHC}	1	per phase, AC-side		6.8		nF
I _{CES} + I _{RD}		$V_{GE} = 0 \text{ V}, V_{CE} = 1200 \text{ V}, T_j = 25 ^{\circ}\text{C}$		4.8		mA
M _{dc}	DC terminals, SI Ur		6		8	Nm
M _{ac}	AC terminals, SI Ur		13		15	Nm
w	SKiiP System w/o h	neat sink		3.1		kg
W _h	heat sink			8		kg

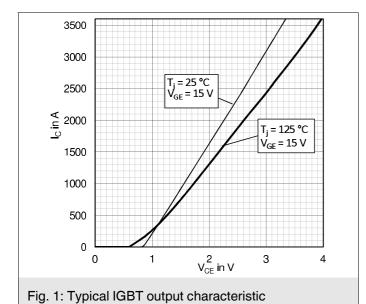


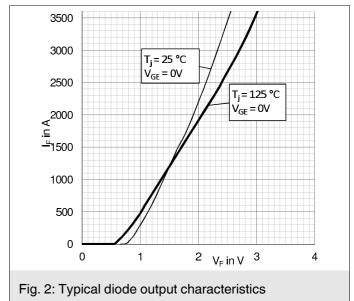
Isolation coordination acc. to EN 50178 and IEC 61800-5-1	
Maximum grid RMS voltage, line-to-line, grounded delta mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, grounded delta mains	2000m
Maximum grid RMS voltage, line-to-line, star point grounded mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, star point grounded mains	5000m
Maximum transient peak voltage between low voltage circuit and mains	1600V
Pollution degree acc. to IEC 60664-1 outside the moulded power section	2
Overvoltage cat. acc. to IEC 60664-1 for mains	III
Basic isolation	between heat sink and mains; between low voltage circuit and mains
Protection level acc. to IEC 60529	IP00

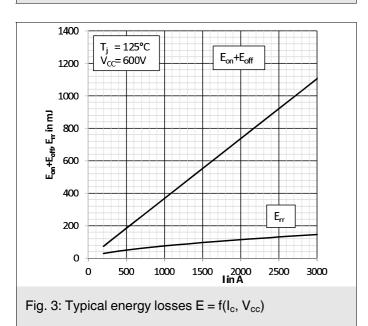
Environmental conditions acc.to IEC 60721

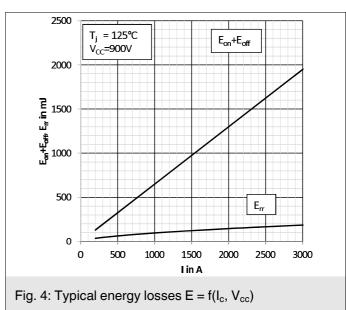
	Storage	Transportation	Operation stationary use at weather protected locations	Operating ground vehicle installations	Operating ship environment
Climatic conditions	1K2 ₍₁₎	2K2 ₍₁₎	3K3 ₍₁₎	5K1 ₍₁₎	
Biological conditions	1B1	2B1	3B1	5B1	6B1
Chemically active substances (excluded: salt spray)	1C2	2C1	3C2	5C2	6C2
Mechanically active substances	181	281	381	581	6S1
Mechanical conditions	1M3	(4)	3M6 ₍₂₎	5M3 ₍₃₎	6M3
Contaminating fluids				5F1	

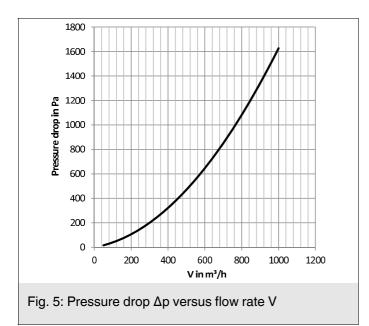
- (1) expanded temperature range: -40°C / +85°C. Please note: by operation near 85°C the life time of product is reduced.
- (2) 3M7 possible, but due to the mechanic load capacity of external components like DC-Link capacitors limited to 3M6
- (3) 5M3 without impact of foreign bodies, stones
- (4) no declaration due to customer-specific packing

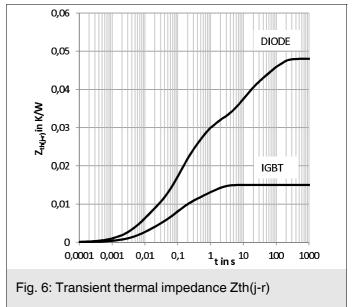


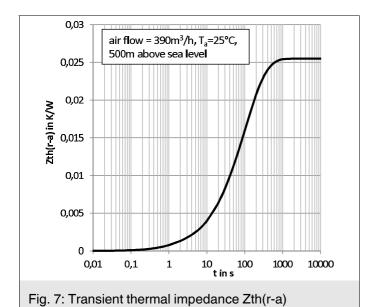












		R _{th} [K/W]						
	1	2	3	4	5	6		
Z _{th(j-r)} I	0,0027	0,0055	0,0022	0,0046	0,0000	0,0000		
Z _{th(j-r)} D	0,0061	0,0126	0,0113	0,0076	0,0019	0,0085		
Z _{th(r-a)}	0,0008	0,0030	0,0120	0,0097	0,0000	0,0000		
	tau [s]							
	1	2	3	4	5	6		
Z _{th(j-r)} I	0,0090	0,0700	0,2200	1,1000	1,0000	1,0000		
Z _{th(j-r)} D	0,0070	0,0850	0,4400	8,3000	12,000	72,000		
Z _{th(r-a)}	1,3800	17,000	82,000	209,00	1,0000	1,0000		

Fig. 8: Coefficients of thermal impedances

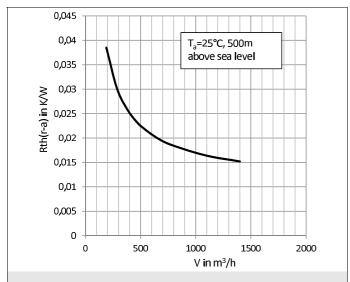
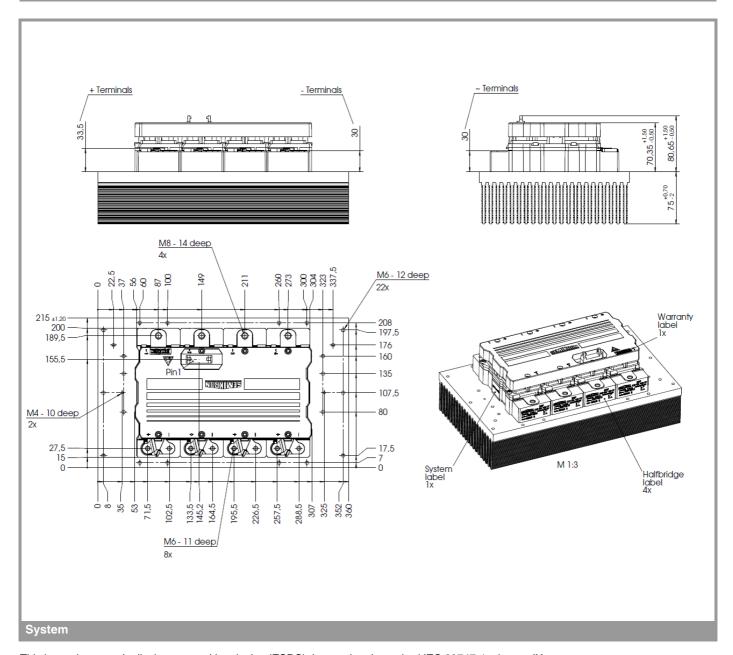


Fig. 9: Thermal resistance Rth(r-a) versus flow rate V



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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